1. General description

The 74LVC1G02 provides the single 2-input NOR function.

Input can be driven from either 3.3 V or 5 V devices. These features allow the use of these devices in a mixed 3.3 V and 5 V environment.

Schmitt-trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ± 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



3. Ordering information

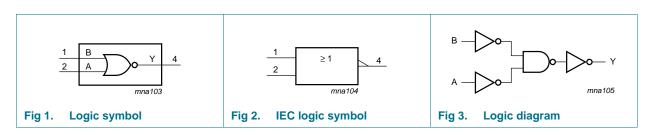
Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G02GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74LVC1G02GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74LVC1G02GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74LVC1G02GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74LVC1G02GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74LVC1G02GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				
74LVC1G02GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74LVC1G02GW	VB
74LVC1G02GV	V02
74LVC1G02GM	VB
74LVC1G02GF	VB
74LVC1G02GN	VB
74LVC1G02GS	VB
74LVC1G02GX	VB

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

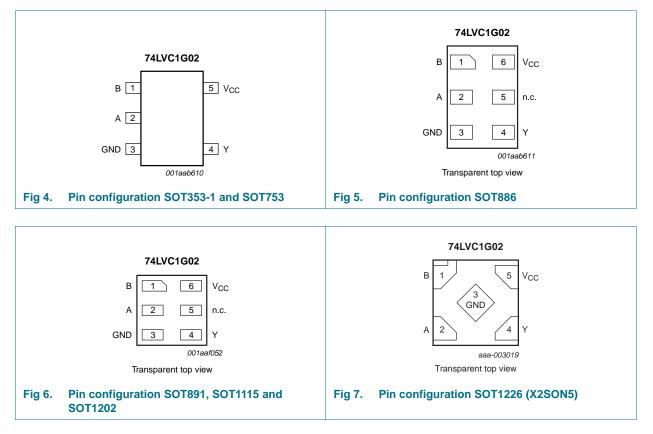
5. Functional diagram



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6. Pinning information

6.1 Pinning



6.2 Pin description

Symbol	Pin		Description	
	TSSOP5 and X2SON5	XSON6		
В	1	1	data input	
A	2	2	data input	
GND	3	3	ground (0 V)	
Y	4	4	data output	
n.c.	-	5	not connected	
V _{CC}	5	6	supply voltage	

7. Functional description

Table 4.	Function table ^[1]		
Inputs			Outputs
Α		В	Y
L		L	н
L		Н	L
Н		L	L
Н		Н	L

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
Symbol	Farameter	Conditions	IVIIN	wax	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
I _{OK}	output clamping current	$V_{O} > V_{CC}$ or $V_{O} < 0 V$	-	±50	mA
Vo	output voltage	Active mode	[1][2] -0.5	$V_{CC} + 0.5$	V
		Power-down mode	[1][2] -0.5	+6.5	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±50	mA
I _{CC}	supply current		-	+100	mA
I _{GND}	ground current		-100	-	mA
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	<u>[3]</u> _	250	mW
T _{stg}	storage temperature		-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0 V$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

9. Recommended operating conditions

Table 6.	Recommended operating condi	tions				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		$V_{CC} = 0 V$; Power-down mode	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	-	-	20	ns/V
		V_{CC} = 2.7 V to 5.5 V	-	-	10	ns/V
		VCC = 2.1 V to 5.5 V			10	

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °	°C to +8	5 °C	-40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
VIH	HIGH-level	V _{CC} = 1.65 V to 1.95 V	$0.65V_{CC}$	-	-	0.65V _{CC}	-	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		V_{CC} = 4.5 V to 5.5 V	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	V
V _{IL}	LOW-level	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	$I_{O} = -100 \ \mu\text{A};$ $V_{CC} = 1.65 \ \text{V} \text{ to } 5.5 \ \text{V}$	$V_{CC}-0.1$	-	-	$V_{CC}-0.1$	-	V
		$I_0 = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	0.95	-	V
		$I_0 = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	1.7	-	V
		$I_0 = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	1.9	-	V
		$I_0 = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	2.0	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	3.4	-	V
V _{OL}	LOW-level	$V_I = V_{IH} \text{ or } V_{IL}$						
	output voltage	$I_{O} = 100 \ \mu$ A; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	-	0.1	V
		$I_0 = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.70	V
		$I_0 = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	-	0.45	V
		$I_0 = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	-	0.60	V
		$I_0 = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.80	V
		$I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	-	0.80	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	±0.1	±5	-	±100	μA
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Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C t	–40 °C to +125 °C		
			Min	Typ <mark>[1]</mark>	Max	Min	Max		
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; \text{ V}_{I} \text{ or } \text{V}_{O} = 5.5 \text{ V}$	-	±0.1	±10	-	±200	μA	
I _{CC}	supply current	$V_{I} = 5.5 V \text{ or GND}; I_{O} = 0 A;$ $V_{CC} = 1.65 V \text{ to } 5.5 V$	-	0.1	10	-	200	μΑ	
ΔI_{CC}	additional supply current		-	5	500	-	5000	μΑ	
CI	input capacitance	V_{CC} = 3.3 V; V_{I} = GND to V_{CC}	-	5	-	-	-	pF	

Table 7. Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8.Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 9.

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit	
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _{pd} pr	propagation delay	A, B to Y; see Figure 8	[2]						
		V_{CC} = 1.65 V to 1.95 V		1.0	3.2	8.0	1.0	10.5	ns
		V_{CC} = 2.3 V to 2.7 V		0.5	2.2	5.5	0.5	7.0	ns
		$V_{CC} = 2.7 V$		0.5	2.5	5.5	0.5	7.0	ns
		V_{CC} = 3.0 V to 3.6 V		0.5	2.1	4.5	0.5	6.0	ns
		V_{CC} = 4.5 V to 5.5 V		0.5	1.7	4.0	0.5	5.5	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC} ; $V_{CC} = 3.3 V$	<u>[3]</u>	-	14	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}{}^2 \times f_o)$ = sum of outputs.



12. Waveforms

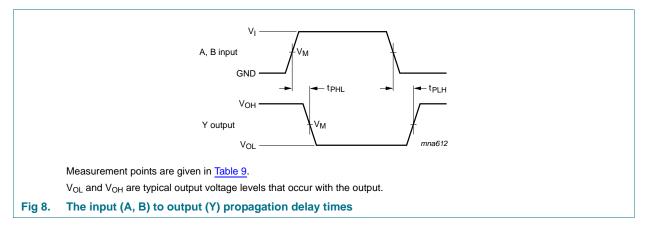
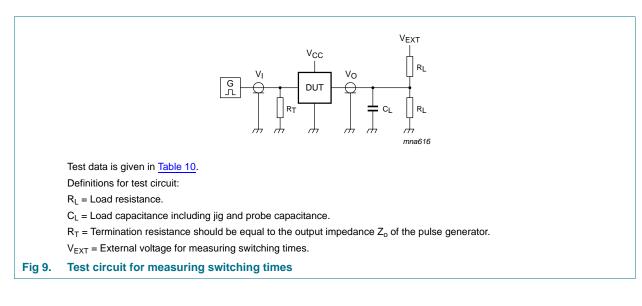


Table 9.Measurement points

Supply voltage	Input	Output	
V _{CC}	V _M	V _M	
1.65 V to 1.95 V	0.5V _{CC}	0.5V _{CC}	
2.3 V to 2.7 V	0.5V _{CC}	0.5V _{CC}	
2.7 V	1.5 V	1.5 V	
3.0 V to 3.6 V	1.5 V	1.5 V	
4.5 V to 5.5 V	0.5V _{CC}	0.5V _{CC}	



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Single 2-input NOR gate

Supply voltage	Input		Load		V _{EXT}
V _{cc}	VI	$t_r = t_f$	CL	RL	t _{PLH} , t _{PHL}
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V _{CC}	\leq 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open



13. Package outline

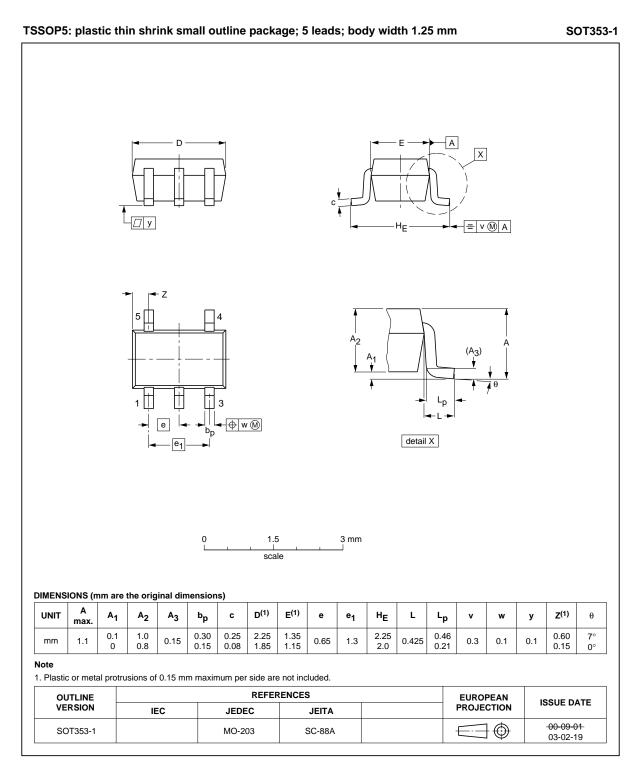
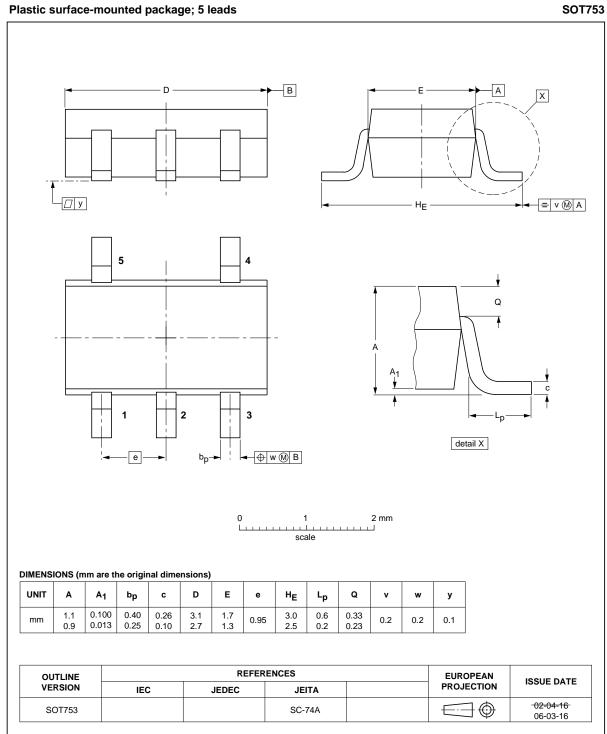


Fig 10. Package outline SOT353-1 (TSSOP5)

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Plastic surface-mounted package; 5 leads

Fig 11. Package outline SOT753 (SC-74A)

Product data sheet

74LVC1G02



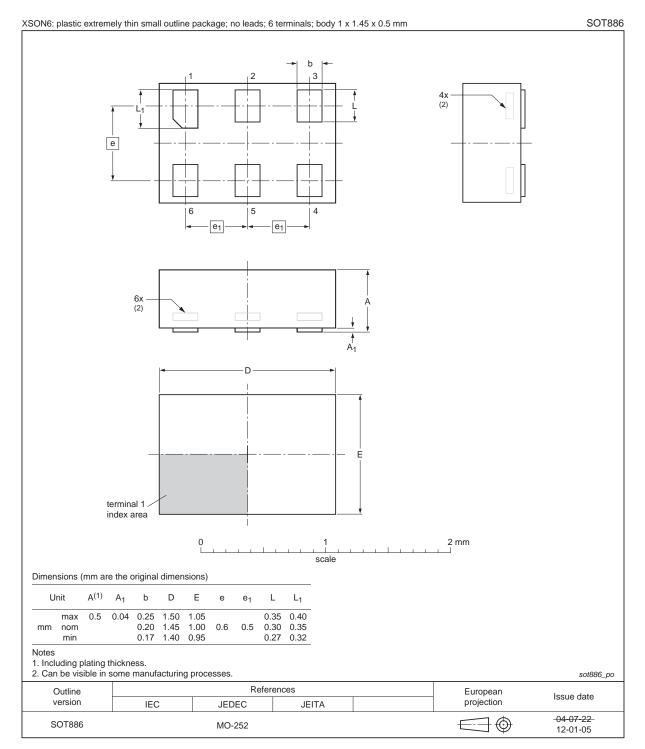


Fig 12. Package outline SOT886 (XSON6)

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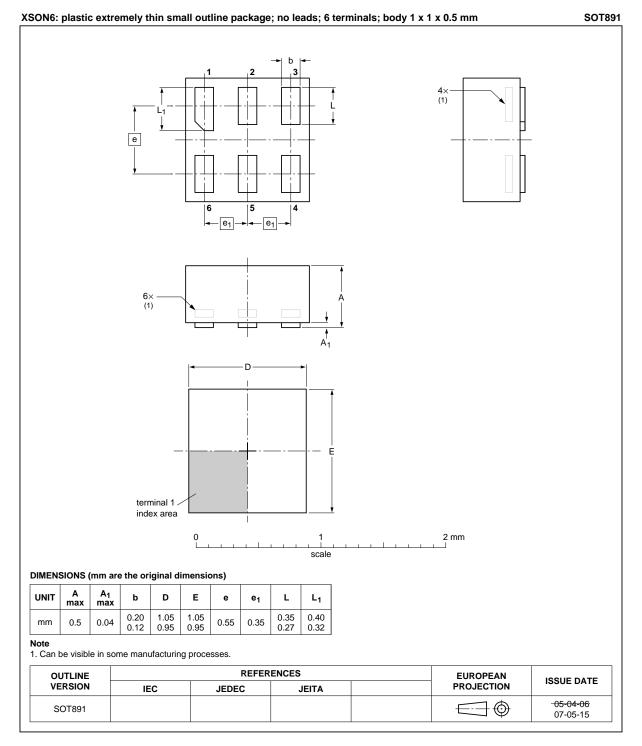
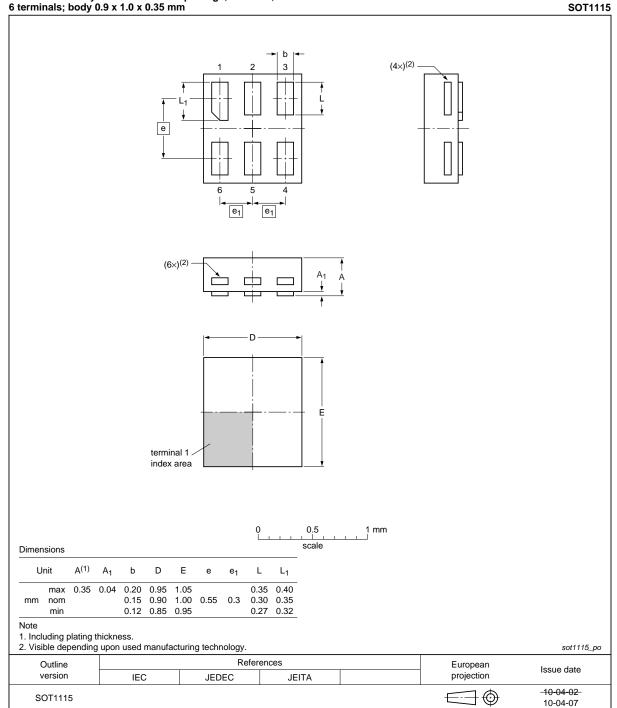


Fig 13. Package outline SOT891 (XSON6)

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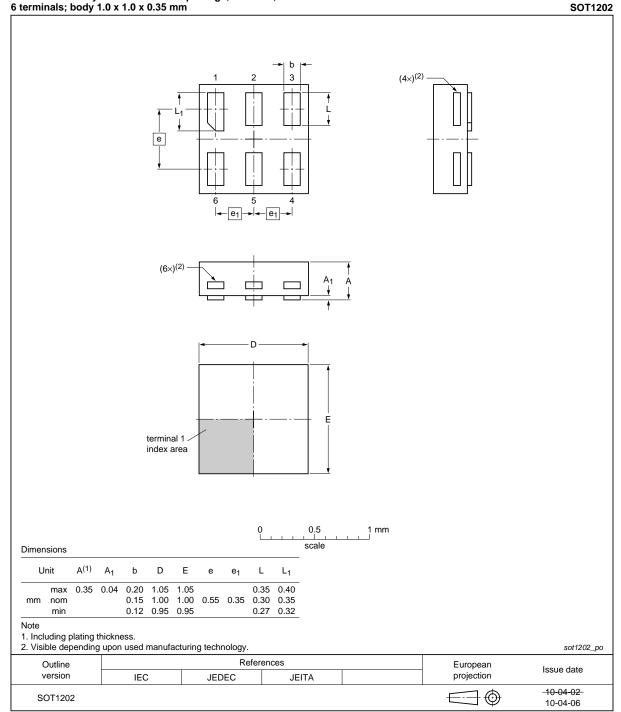


XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 14. Package outline SOT1115 (XSON6)

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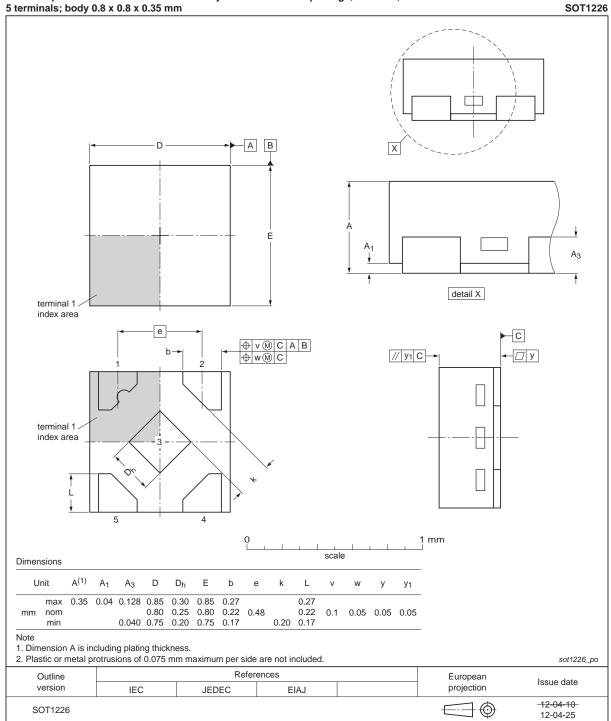


XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)

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X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals: body 0.8 x 0.8 x 0.35 mm

Fig 16. Package outline SOT1226 (X2SON5)

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Product data sheet



14. Abbreviations

AcronymDescriptionCMOSComplementary Metal Oxide SemiconductorDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelTTLTransistor-Transistor Logic	Table 11. Abbreviations			
DUT Device Under Test ESD ElectroStatic Discharge HBM Human Body Model MM Machine Model	Acronym	Description		
ESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	CMOS	Complementary Metal Oxide Semiconductor		
HBM Human Body Model MM Machine Model	DUT	Device Under Test		
MM Machine Model	ESD	ElectroStatic Discharge		
	HBM	Human Body Model		
TTL Transistor-Transistor Logic	MM	Machine Model		
	TTL	Transistor-Transistor Logic		

15. Revision history

Table 12. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G02 v.11	20120629	Product data sheet	-	74LVC1G02 v.10
Modifications:	 Added type r 	number 74LVC1G02GX (SOT1	226)	
74LVC1G02 v.10	20120305	Product data sheet	-	74LVC1G02 v.9
Modifications:	 Package out 	line drawing of SOT886 (Figure	e 12) modified.	
74LVC1G02 v.9	20111209	Product data sheet	-	74LVC1G02 v.8
Modifications:	 Legal pages 	updated.		
74LVC1G02 v.8	20101020	Product data sheet	-	74LVC1G02 v.7
74LVC1G02 v.7	20070718	Product data sheet	-	74LVC1G02 v.6
74LVC1G02 v.6	20060914	Product data sheet	-	74LVC1G02 v.5
74LVC1G02 v.5	20040907	Product specification	-	74LVC1G02 v.4
74LVC1G02 v.4	20021002	Product specification	-	74LVC1G02 v.3
74LVC1G02 v.3	20020515	Product specification	-	74LVC1G02 v.2
74LVC1G02 v.2	20010411	Product specification	-	74LVC1G02 v.1
74LVC1G02 v.1	20001114	Product specification	-	-

16. Legal information

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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74LVC1G02

Single 2-input NOR gate

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